

# S71NS-R Memory Subsystem Solutions

**MirrorBit® 1.8 Volt-only Simultaneous Read/Write,  
Burst Mode Multiplexed Flash Memory and Burst Mode  
pSRAM**

**512 Mb (32 Mb x 16-bit) and 256 Mb (16 Mb x 16-bit) Flash,  
128 Mb (8 Mb x 16-bit) and 64 Mb (4 Mb x 16-bit) pSRAM**

*Data Sheet*

---



**Notice to Readers:** This document states the current technical specifications regarding the Spansion product(s) described herein. Each product described herein may be designated as Advance Information, Preliminary, or Full Production. See [Notice On Data Sheet Designations](#) for definitions.

## Notice On Data Sheet Designations

Spansion Inc. issues data sheets with Advance Information or Preliminary designations to advise readers of product information or intended specifications throughout the product life cycle, including development, qualification, initial production, and full production. In all cases, however, readers are encouraged to verify that they have the latest information before finalizing their design. The following descriptions of Spansion data sheet designations are presented here to highlight their presence and definitions.

### Advance Information

The Advance Information designation indicates that Spansion Inc. is developing one or more specific products, but has not committed any design to production. Information presented in a document with this designation is likely to change, and in some cases, development on the product may discontinue. Spansion Inc. therefore places the following conditions upon Advance Information content:

“This document contains information on one or more products under development at Spansion Inc. The information is intended to help you evaluate this product. Do not design in this product without contacting the factory. Spansion Inc. reserves the right to change or discontinue work on this proposed product without notice.”

### Preliminary

The Preliminary designation indicates that the product development has progressed such that a commitment to production has taken place. This designation covers several aspects of the product life cycle, including product qualification, initial production, and the subsequent phases in the manufacturing process that occur before full production is achieved. Changes to the technical specifications presented in a Preliminary document should be expected while keeping these aspects of production under consideration. Spansion places the following conditions upon Preliminary content:

“This document states the current technical specifications regarding the Spansion product(s) described herein. The Preliminary status of this document indicates that product qualification has been completed, and that initial production has begun. Due to the phases of the manufacturing process that require maintaining efficiency and quality, this document may be revised by subsequent versions or modifications due to changes in technical specifications.”

### Combination

Some data sheets contain a combination of products with different designations (Advance Information, Preliminary, or Full Production). This type of document distinguishes these products and their designations wherever necessary, typically on the first page, the ordering information page, and pages with the DC Characteristics table and the AC Erase and Program table (in the table notes). The disclaimer on the first page refers the reader to the notice on this page.

### Full Production (No Designation on Document)

When a product has been in production for a period of time such that no changes or only nominal changes are expected, the Preliminary designation is removed from the data sheet. Nominal changes may include those affecting the number of ordering part numbers available, such as the addition or deletion of a speed option, temperature range, package type, or  $V_{IO}$  range. Changes may also include those needed to clarify a description or to correct a typographical error or incorrect specification. Spansion Inc. applies the following conditions to documents in this category:

“This document states the current technical specifications regarding the Spansion product(s) described herein. Spansion Inc. deems the products to have been in sufficient production volume such that subsequent versions of this document are not expected to change. However, typographical or specification corrections, or modifications to the valid combinations offered may occur.”

Questions regarding these document designations may be directed to your local sales office.

# S71NS-R Memory Subsystem Solutions

## MirrorBit® 1.8 Volt-only Simultaneous Read/Write, Burst Mode Multiplexed Flash Memory and Burst Mode pSRAM

512 Mb (32 Mb x 16-bit) and 256 Mb (16 Mb x 16-bit) Flash,  
128 Mb (8 Mb x 16-bit) and 64 Mb (4 Mb x 16-bit) pSRAM



*Data Sheet*

---

### Features

- Power supply voltage of 1.7 V to 1.95 V
- Burst Speed (Flash and pSRAM): 104 MHz
- MCP BGA Package
  - 56 ball, 9.2 x 8.0 mm, 0.5 mm ball pitch
  - 56 ball, 7.7 x 6.2 mm, 0.5 mm ball pitch
- Operating Temperature
  - Wireless, -25°C to +85°C

### General Description

The S71NS-R Series is a product line of stacked Multi-Chip Package (MCP) memory solutions and consists of the following items:

- One or more S29NS-R flash memory die
- One or more pSRAM

The products covered by this document are listed in the table below. For details about their specifications, please refer to their individual data sheet for further details.

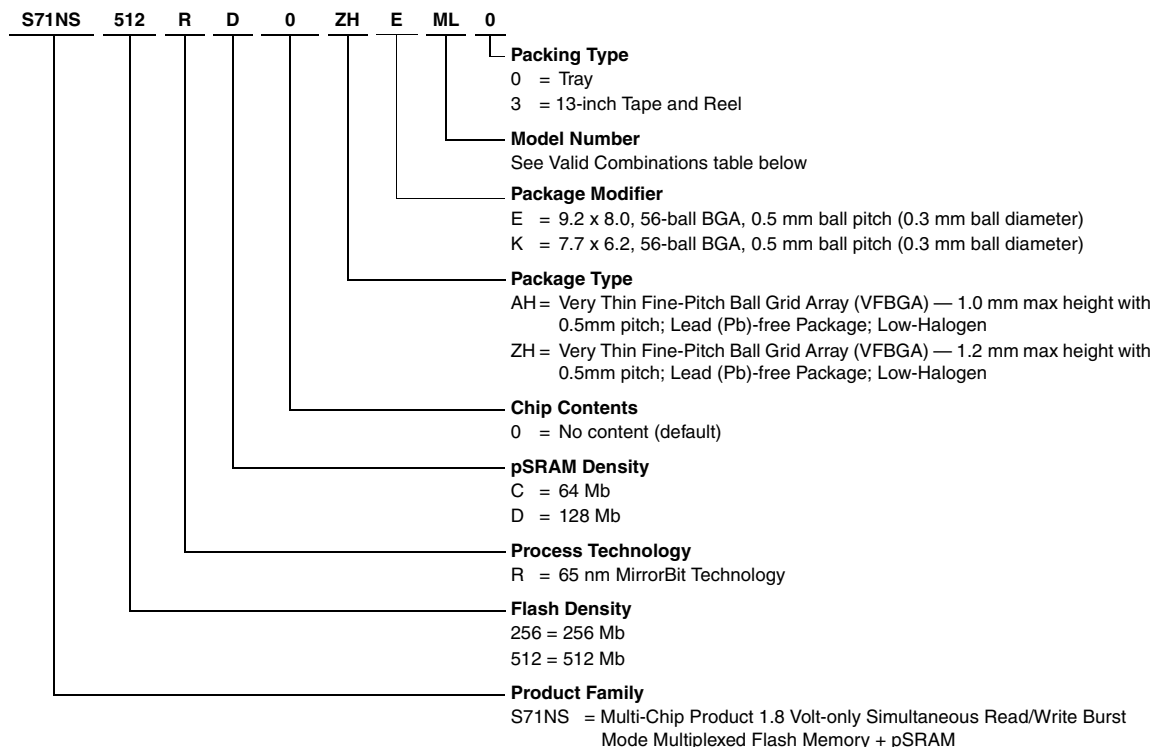
Flash Density	pSRAM Density	Product
512 Mb	128 Mb	S71NS512RD0
256 Mb	128 Mb	S71NS256RD0
256 Mb	64 Mb	S71NS256RC0

For detailed specifications, please refer to the individual data sheets:

Document	Publication Identification Number
S29NS-R	S29NS-R_00
128 Mb MUX pSRAM Type 5	psram_39
128 Mb CellularRAM Address/Data multiplexed	SWM128D108M1R
64 Mb CellularRAM Address/Data multiplexed	SWM064D108M1N

# 1. Ordering Information

The order number is formed by a valid combinations of the following:



## 1.1 Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult your local sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Base Ordering Part Number	Package	Model Number	Packing Type	pSRAM Type	MCP Speed	Boot	Package Type
S71NS512RD0	ZHE	ML	0, 3	SWM128D108M1R	104 MHz	Uniform	NLB056
		KL		MUX pSRAM Type 5			
S71NS256RD0	AHK	KL		MUX pSRAM Type 5		Top	
S71NS256RC0		JL		SWM064D108M1N			

## 2. Input/Output Descriptions

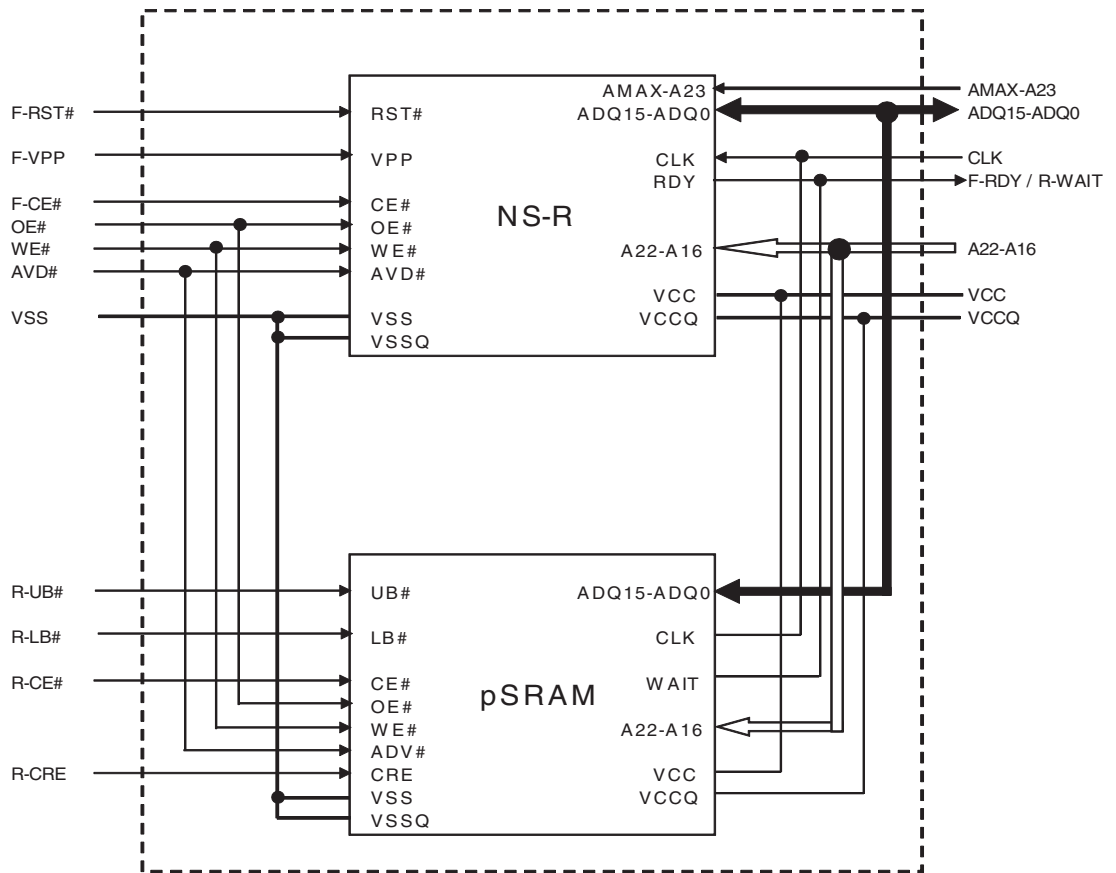
Table 2.1 identifies the input and output package connections provided on the device.

**Table 2.1** Input/Output Descriptions

Symbol	Description	Flash	RAM
AMAX – A16	Address inputs	X	X
A/DQ15-A/DQ0	Multiplexed Address/Data	X	X
OE#	Output Enable input. Asynchronous relative to CLK for the Burst mode.	X	X
WE#	Write Enable input.	X	X
V <sub>SS</sub>	Ground	X	X
V <sub>SSQ</sub>	Input/Output Ground	X	X
F-RDY/R-WAIT	Ready output; indicates the status of the Burst read. Flash Memory RDY (using default "Active HIGH" configuration) V <sub>OL</sub> = data invalid V <sub>OH</sub> = data valid Note: The default polarity for the pSRAM WAIT signal is opposite the default polarity of the Flash RDY signal. pSRAM WAIT (using default "Active HIGH" configuration) V <sub>OL</sub> = data valid V <sub>OH</sub> = data invalid To match polarities, change bit 10 of the pSRAM Bus Configuration Register to 0 (Active LOW WAIT). Alternately, change bit 10 of the Flash Configuration Register to 0 (Active LOW RDY)	X	X
CLK	Clock input. In burst mode, after the initial word is output, subsequent active edges of CLK increment the internal address counter. Should be at V <sub>IL</sub> or V <sub>IH</sub> while in asynchronous mode	X	X
AVD#	Address Valid input. Indicates to device that the valid address is present on the address inputs. Low = for asynchronous mode, indicates valid address; for burst mode, causes starting address to be latched. High = device ignores address inputs	X	X
F-RST#	Hardware reset input. Low = device resets and returns to reading array data	X	
F-WP#	Hardware write protect input. At V <sub>IL</sub> , disables program and erase functions in the four outermost sectors. Should be at V <sub>IH</sub> for all other conditions.	X	
F-V <sub>PP</sub>	Accelerated input. At V <sub>IH</sub> , accelerates programming; automatically places device in unlock bypass mode. At V <sub>IL</sub> , disables all program and erase functions. Should be at V <sub>IH</sub> for all other conditions.	X	
R-CE#	Chip-enable input for pSRAM.		X
F-CE#	Chip-enable input for Flash. Asynchronous relative to CLK for Burst Mode.	X	
R-CRE	Control Register Enable (pSRAM).		X
V <sub>CC</sub>	Flash and pSRAM 1.8 Volt-only single power supply.	X	X
V <sub>CCQ</sub>	Flash and pSRAM Input/Output Power Supply	X	X
R-UB#	Upper Byte Control (pSRAM).		X
R-LB#	Lower Byte Control (pSRAM)		X
DNU	Do Not Use. A device internal signal may be connected to the package connector. The connection may be used by Spansion for test or other purposes and is not intended for connection to any host system signal. Any DNU signal related function will be inactive when the signal is at V <sub>IL</sub> . The signal has an internal pull-down resistor and may be left unconnected in the host system or may be tied to V <sub>SS</sub> . Do not use these connections for PCB signal routing channels. Do not connect any host system signal to these connections.		
NC	Not Connected. No device internal signal is connected to the package connector nor is there any future plan to use the connector for a signal. The connection may safely be used for routing space for a signal on a Printed Circuit Board (PCB).		
RFU	Reserved For Future Use. No device internal signal is currently connected to the package connector but there is potential future use for the connector for a signal. It is recommended to not use RFU connectors for PCB routing channels so that the PCB may take advantage of future enhanced features in compatible footprint devices.		

### 3. MCP Block Diagram

Figure 3.1 MCP Block Diagram



## 4. Connection Diagrams/Physical Dimensions

This section contains the I/O designations and package specifications for the S71NS-R.

### 4.1 Special Handling Instructions for FBGA Packages

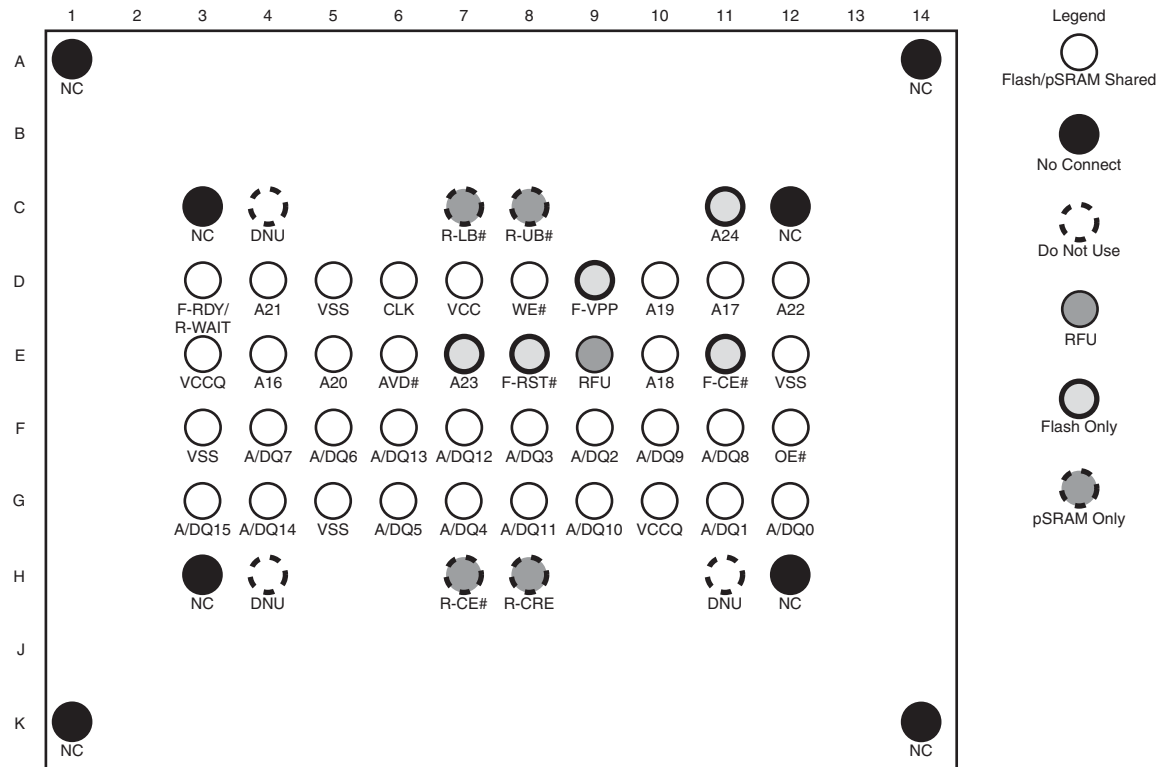
Special handling is required for Flash Memory products in FBGA packages.

Flash memory devices in FBGA packages may be damaged if exposed to ultrasonic cleaning methods. The package and/or data integrity may be compromised if the package body is exposed to temperatures above 150°C for prolonged periods of time.

### 4.2 Connection Diagrams

Figure 4.1 56-ball Fine-Pitch Ball Grid Array

(Top View, Balls Facing Down)



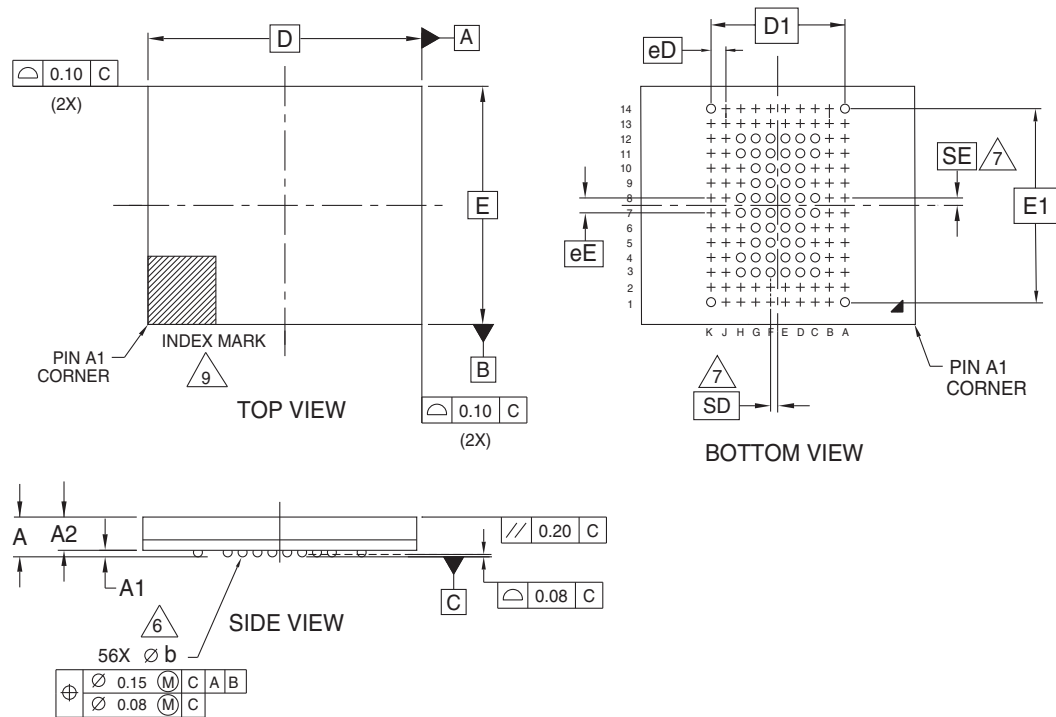
**Note:**

Addresses are shared between Flash and RAM depending on the density of the pSRAM.

MCP	Flash-Only Addresses	Shared Addresses	Shared ADQ Pins
S71NS512RD0	A24-A23	A22-A16	A/DQ15-A/DQ0
S71NS256RD0	A23	A22-A16	A/DQ15-A/DQ0
S71NS256RC0	A23-A22	A21-A16	A/DQ15-A/DQ0

### 4.3 Physical Dimensions

Figure 4.2 NLB056—56-ball VFBGA 9.2 x 8.0 mm



NOTES:

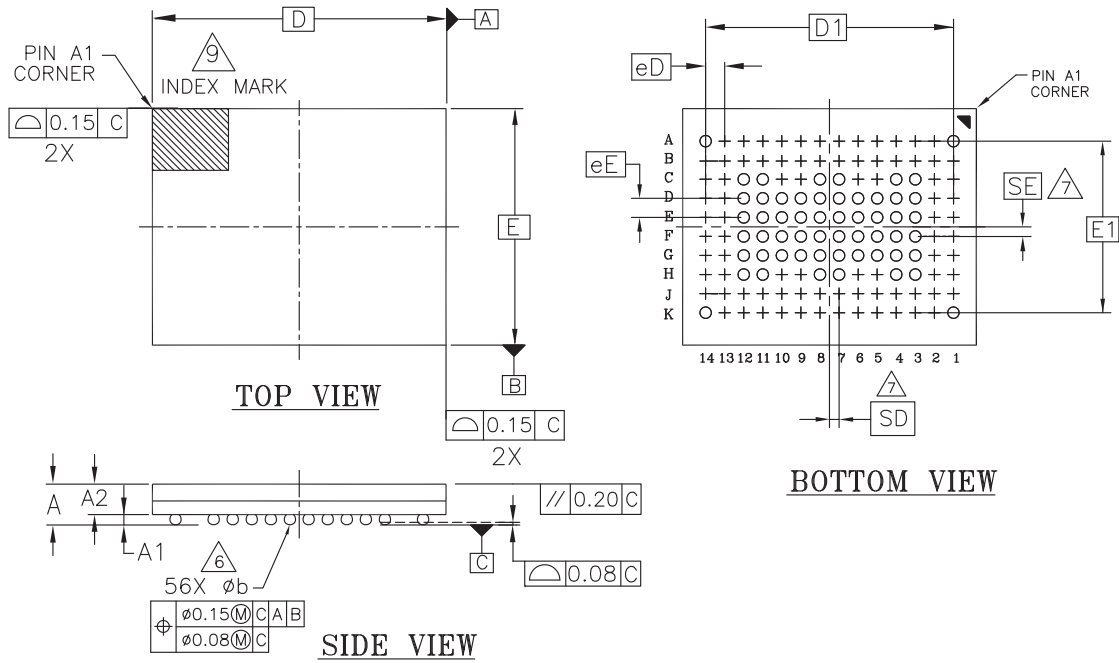
- DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994.
  - ALL DIMENSIONS ARE IN MILLIMETERS.
  - BALL POSITION DESIGNATION PER JEP95, SECTION 4.3, SPP-010.
  - $\square$  REPRESENTS THE SOLDER BALL GRID PITCH.
  - SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION.  
SYMBOL "ME" IS THE BALL MATRIX SIZE IN THE "E" DIRECTION.  
n IS THE NUMBER OF POPULATED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.
  - $\triangle 6$  DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.
  - $\triangle 7$  SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW.
- WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW SD OR SE = 0.000.
- WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE =  $\lfloor \frac{eD}{2} \rfloor$
- "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.
  - $\triangle 9$  A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.
  - OUTLINE AND DIMENSIONS PER CUSTOMER REQUIREMENT.

PACKAGE	NLB 056			
JEDEC	N/A			
D x E	9.20 mm x 8.00 mm PACKAGE			
SYMBOL	MIN	NOM	MAX	NOTE
A	---	---	1.20	PROFILE
A1	0.20	---	---	BALL HEIGHT
A2	0.85	---	0.97	BODY THICKNESS
D	9.20 BSC.			BODY SIZE
E	8.00 BSC.			BODY SIZE
D1	4.50 BSC.			MATRIX FOOTPRINT
E1	6.50 BSC.			MATRIX FOOTPRINT
MD	10			MATRIX SIZE D DIRECTION
ME	14			MATRIX SIZE E DIRECTION
n	56			BALL COUNT
Øb	0.25	0.30	0.35	BALL DIAMETER
eE	0.50 BSC.			BALL PITCH
eD	0.50 BSC.			BALL PITCH
SD / SE	0.25 BSC.			SOLDER BALL PLACEMENT
	A2 - A13,B1 - B14 C1,C2,C5,C6,C9,C10,C13,C14 D1,D2,D13,D14,E1,E2,E13,E14,F1,F2,F13,F14 G1,G2,G13,G14,H1,H2,H5,H6,H9,H10,H13,H14 J1 - J14, K2 - K13			DEPOPULATED SOLDER BALLS

35071\_16-038.22\7.14.5



Figure 4.3 RSD056—56-ball VFBGA 7.7 x 6.2 mm



PACKAGE	RSD 056			NOTE
JEDEC	N/A			
D x E	7.70 mm x 6.20 mm PACKAGE			
SYMBOL	MIN	NOM	MAX	
A	0.80	0.90	1.00	PROFILE
A1	0.18	---	---	BALL HEIGHT
A2	0.62	---	0.74	BODY THICKNESS
D	7.70 BSC			BODY SIZE
E	6.20 BSC			BODY SIZE
D1	6.50 BSC			MATRIX FOOTPRINT
E1	4.50 BSC			MATRIX FOOTPRINT
MD	14			MATRIX SIZE D DIRECTION
ME	10			MATRIX SIZE E DIRECTION
n	56			BALL COUNT
$\phi b$	0.25	0.30	0.35	BALL DIAMETER
eE	0.50 BSC			BALL PITCH
eD	0.50 BSC			BALL PITCH
SE SD	0.25 BSC			SOLDER BALL PLACEMENT
	A2-A9, B1-B10, C1,C2,C9,10,D1,D2,D9,D10 E1,E2,E3,E8,E9,E10,F1,F2,F3,F8,F9,F10,G1,G2,G9,G10 H1,H2,H9,H10,I1,I2,I3,I8,I9,I10,K1,K2,K3,K8,K9,K10 L1,L2,L9,L10,M1,M2,M9,M10, N1-N10, P2-P9			DEPOPULATED SOLDER BALLS

NOTES:

- DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- BALL POSITION DESIGNATION PER JEP95, SECTION 4.3, SPP-010.
- [e] REPRESENTS THE SOLDER BALL GRID PITCH.
- SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION.  
SYMBOL "ME" IS THE BALL MATRIX SIZE IN THE "E" DIRECTION.  
n IS THE NUMBER OF POPULATED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.
- DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.
- SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW.  
WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW SD OR SE = 0.000.  
WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = [e/2]
- "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.
- A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.
- OUTLINE AND DIMENSIONS PER CUSTOMER REQUIREMENT.

3719 \ 116-038.63 \ 1.26.9

## 5. Revision History

Section	Description
<b>Revision 01 (January 14, 2008)</b>	
	Initial release
<b>Revision 02 (February 11, 2008)</b>	
Global	Added OPN S71NS256RC0ZHKJL
<b>Revision 03 (September 10, 2008)</b>	
Global	Added OPN S71NS512RD0ZHEKL
<b>Revision 04 (October 6, 2008)</b>	
Global	Removed OPNs S71NS256RC0ZHKJL, S71NS256RD0ZHEJL, and S71NS512RD0ZHEJL
Physical Dimensions	Removed packages NLD056 and NSB056
<b>Revision 05 (April 9, 2009)</b>	
Physical Dimensions	Updated package drawing for NLB056
<b>Revision 06 (July 23, 2009)</b>	
Global	Added OPN S71NS256RD0AHKKL0, S71NS256RC0AHKJL0
General Description	Added 256 Mb Flash and 64 Mb pSRAM
Valid Combinations	Added Package Type to table
Physical Dimensions	Added figure RSD056—56-ball VFBGA 7.7 x 6.2 mm
<b>Revision 07 (August 3, 2010)</b>	
General Description	Updated MUX pSRAM Type 3 to SWM064D108M1N. Added reference for SWM128D133M1R.
Ordering Information	Removed 7 inch Tape and Reel option.
Valid Combinations	Added OPN S71NS512RD0ZHEML Updated MUX pSRAM Type 3 entries to SWM064D108M1N.
Input/Output Descriptions	Refreshed DNU, NC, RFU definitions
MCP Block Diagram	Updated MCP Block Diagram
Connection Diagrams	Updated 56-ball Fine-Pitch Ball Grid Array

### **Colophon**

The products described in this document are designed, developed and manufactured as contemplated for general use, including without limitation, ordinary industrial use, general office use, personal use, and household use, but are not designed, developed and manufactured as contemplated (1) for any use that includes fatal risks or dangers that, unless extremely high safety is secured, could have a serious effect to the public, and could lead directly to death, personal injury, severe physical damage or other loss (i.e., nuclear reaction control in nuclear facility, aircraft flight control, air traffic control, mass transport control, medical life support system, missile launch control in weapon system), or (2) for any use where chance of failure is intolerable (i.e., submersible repeater and artificial satellite). Please note that Spansion will not be liable to you and/or any third party for any claims or damages arising in connection with above-mentioned uses of the products. Any semiconductor devices have an inherent chance of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions. If any products described in this document represent goods or technologies subject to certain restrictions on export under the Foreign Exchange and Foreign Trade Law of Japan, the US Export Administration Regulations or the applicable laws of any other country, the prior authorization by the respective government entity will be required for export of those products.

### **Trademarks and Notice**

The contents of this document are subject to change without notice. This document may contain information on a Spansion product under development by Spansion. Spansion reserves the right to change or discontinue work on any product without notice. The information in this document is provided as is without warranty or guarantee of any kind as to its accuracy, completeness, operability, fitness for particular purpose, merchantability, non-infringement of third-party rights, or any other warranty, express, implied, or statutory. Spansion assumes no liability for any damages of any kind arising out of the use of the information in this document.

Copyright © 2008-2010 Spansion Inc. All rights reserved. Spansion®, the Spansion Logo, MirrorBit®, MirrorBit® Eclipse™, ORNAND™, EcoRAM™ and combinations thereof, are trademarks and registered trademarks of Spansion LLC in the United States and other countries. Other names used are for informational purposes only and may be trademarks of their respective owners.